

isc N-Channel MOSFET Transistor

IXTH5N100

FEATURES

- Drain Current I_D= 5A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}= 1000V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 2.4 \Omega (Max)$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



DESCRIPTION

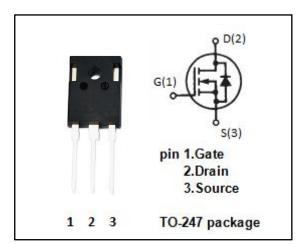
• Designed for use in switch mode power supplies and general purpose applications.

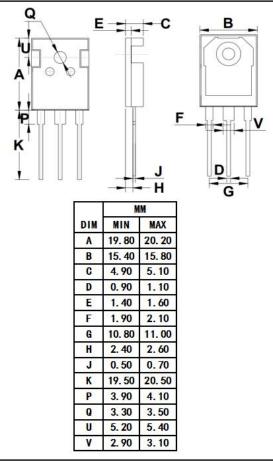
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage		V
V _{GS}	Gate-Source Voltage-Continuous ±20		V
ID	Drain Current-Continuous 5		Α
I _{DM}	Drain Current-Single Pluse 20		Α
P _D	Total Dissipation @Tc=25°C 180		W
TJ	Max. Operating Junction Temperature	ion Temperature -55~150	
T _{stg}	Storage Temperature -55~150		$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.7	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 3mA	1000		V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 250μA	2	4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 2.5A		2.4	Ω
Igss	Gate-Body Leakage Current	V _{GS} =±20V;V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 800V; V _{GS} = 0 V _{DS} = 800V; V _{GS} = 0;T _J =125℃		250 1000	μA
V _{SD}	Forward On-Voltage	I _S =5A; V _{GS} = 0		1.5	V

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